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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email \& Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, \#122 Zhenhua RD., Futian, Shenzhen, China

## Features

- Broad frequency support from 9 kHz to 26.5 GHz
- High port to port isolation
- 63 dB @ 3 GHz
- 58 dB @ 7.5 GHz
- 39 dB @ 13.5 GHz
- 28 dB @ 20 GHz
- 22 dB @ 26.5 GHz
- HaRPTM technology enhanced
- Fast settling time
- No gate and phase lag
- No drift in insertion loss and phase
- Improved high frequency insertion loss and return loss performance with external matching
- High ESD performance of 3.5 kV HBM on all pins
- Packaging - 29-lead $4 \times 4$ mm LGA


## Applications

- Test and measurement
- Microwave backhaul
- Radar


## Product Description

The PE42522 is a HaRPTM technology-enhanced absorptive SPDT RF switch that supports a broad frequency range from 9 kHz to 26.5 GHz . This broadband general purpose switch offers excellent isolation, high linearity performance and has exceptional settling time making this device ideal for many broadband wireless applications. No blocking capacitors are required if DC voltage is not present on the RF ports.
The PE42522 is manufactured on Peregrine's UltraCMOS ${ }^{\circledR}$ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate.
Peregrine's HaRP technology enhancements deliver high linearity and excellent harmonics performance. It is an innovative feature of the UltraCMOS process, offering the performance of GaAs with the economy and integration of conventional CMOS.

## Optional External $\mathrm{V}_{\mathrm{SS}}$ Control

For proper operation, the $\mathrm{V}_{\text {SS_EXT }}$ control pin must be grounded or tied to the $\mathrm{V}_{\text {SS }}$ voltage specified in Table 2. When the $\mathrm{V}_{\text {SS_EXT }}$ control pin is grounded, FETs in the switch are biased with an internal negative voltage generator. For applications that require the lowest possible spur performance, $\mathrm{V}_{\text {Ss Ext }}$ can be applied externally to bypass the internal negative voltage generator.

## Absolute Maximum Ratings

Exceeding absolute maximum ratings listed in Table 1 may cause permanent damage. Operation should be restricted to the limits in Table 2. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

## ESD Precautions

When handling this UltraCMOS device, observe the same precautions as with any other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in Table 1.

## Latch-up Immunity

Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.
Table 1•Absolute Maximum Ratings for PE42522

| Parameter/Condition | Min | Max | Unit |
| :---: | :---: | :---: | :---: |
| Supply voltage, $\mathrm{V}_{\mathrm{DD}}$ | -0.3 | 5.5 | V |
| Digital input voltage, V1 | -0.3 | 3.6 | V |
| $\begin{aligned} & \text { RF input power, CW (RFC-RFX) }{ }^{(1)} \\ & \quad 9 \mathrm{kHz}-2.89 \mathrm{MHz} \\ & \quad>2.89 \mathrm{MHz}-18 \mathrm{GHz} \\ & >18-26.5 \mathrm{GHz} \end{aligned}$ |  | Fig. 2, Fig. 3 33 <br> Fig. 4 | dBm <br> dBm <br> dBm |
| $\begin{aligned} & \text { RF input power, pulsed (RFC-RFX) }{ }^{(2)} \\ & \quad 9 \mathrm{kHz}-2.89 \mathrm{MHz} \\ & \quad>2.89 \mathrm{MHz}-18 \mathrm{GHz} \\ & \quad>18-26.5 \mathrm{GHz} \end{aligned}$ |  | Fig. 2, Fig. 3 34 <br> Fig. 4 | dBm <br> dBm <br> dBm |
| $\begin{aligned} & \text { RF input power into terminated ports, CW }(\mathrm{RFX})^{(1)} \\ & \quad 9 \mathrm{kHz}-1.39 \mathrm{MHz} \\ & \quad>1.39 \mathrm{MHz}-18 \mathrm{GHz} \\ & \quad>18-26.5 \mathrm{GHz} \end{aligned}$ |  | Fig. 2, Fig. 3 22 <br> Fig. 4 | dBm <br> dBm <br> dBm |
| Storage temperature range | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| ESD voltage HBM, all pins ${ }^{(3)}$ |  | 3500 | V |
| ESD voltage MM, all pins ${ }^{(4)}$ |  | 150 | V |
| ESD voltage CDM, all pins ${ }^{(5)}$ |  | 500 | V |

Table 1• Absolute Maximum Ratings for PE42522 (Cont.)

Notes:

1) $100 \%$ duty cycle, all bands, $50 \Omega$.
2) Pulsed, $5 \%$ duty cycle of $4620 \mu \mathrm{~s}$ period, $50 \Omega$.
3) Human body model (MIL-STD 883 Method 3015).
4) Machine model (JEDEC JESD22-A115).
5) Charged device model (JEDEC JESD22-C101).

## Recommended Operating Conditions

Table 2 list the recommending operating condition for PE42522. Devices should not be operated outside the recommended operating conditions listed below.

Table $2 \cdot$ Recommended Operating Condition for PE42522

| Parameter | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Normal mode ( $\left.\mathrm{V}_{\text {SS_EXT }}=0 \mathrm{~V}\right)^{(1)}$ |  |  |  |  |
| Supply voltage, $\mathrm{V}_{\mathrm{DD}}$ | 2.3 |  | 5.5 | V |
| Supply current, $\mathrm{I}_{\mathrm{DD}}$ |  | 120 | 200 | $\mu \mathrm{A}$ |
| Bypass mode ( $\left.\mathrm{VSS}_{\text {SEXT }}=\mathbf{- 3 . 4 V}\right)^{(2)}$ |  |  |  |  |
| Supply voltage, $\mathrm{V}_{\mathrm{DD}}$ <br> ( $\mathrm{V}_{\mathrm{DD}} \geq 3.4 \mathrm{~V}$ for Table 3 full spec. compliance) | 2.7 | 3.4 | 5.5 | V |
| Supply current, IDD |  | 50 | 80 | $\mu \mathrm{A}$ |
| Negative supply voltage, $\mathrm{V}_{\text {SS_EXT }}$ | -3.6 |  | -3.2 | V |
| Negative supply current, ISS | -40 | -16 |  | $\mu \mathrm{A}$ |
| Normal or Bypass mode |  |  |  |  |
| Digital input high, V1 | 1.17 |  | 3.6 | V |
| Digital input low, V1 | -0.3 |  | 0.6 | V |
| $\begin{array}{\|l} \text { RF input power, CW (RFC-RFX) }{ }^{(3)} \\ \quad 9 \mathrm{kHz}-2.89 \mathrm{MHz} \\ \quad>2.89 \mathrm{MHz}-18 \mathrm{GHz} \\ \quad>18-26.5 \mathrm{GHz} \end{array}$ |  |  | Fig. 2, Fig. 3 <br> 30 <br> Fig. 4 | dBm <br> dBm <br> dBm |
| $\begin{aligned} & \text { RF input power, pulsed (RFC-RFX) }{ }^{(4)} \\ & \quad 9 \mathrm{kHz}-2.89 \mathrm{MHz} \\ & \quad>2.89 \mathrm{MHz}-18 \mathrm{GHz} \\ & \quad>18-26.5 \mathrm{GHz} \end{aligned}$ |  |  | Fig. 2, Fig. 3 <br> 32 <br> Fig. 4 | dBm <br> dBm <br> dBm |

Table 2•Recommended Operating Condition for PE42522 (Cont.)

| Parameter | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| RF input power into terminated ports, $\mathrm{CW}(\mathrm{RFX})^{(3)}$ $\begin{aligned} & 9 \mathrm{kHz}-1.39 \mathrm{MHz} \\ & >1.39 \mathrm{MHz}-18 \mathrm{GHz} \\ & >18-26.5 \mathrm{GHz} \end{aligned}$ |  |  | Fig. 2, Fig. 3 20 <br> Fig. 4 | dBm <br> dBm <br> dBm |
| Operating temperature range, $\mathrm{T}_{\mathrm{OP}}$ | -40 | +25 | +85 | ${ }^{\circ} \mathrm{C}$ |

Notes:

1) Normal mode: connect $V_{\text {SS_EXT }}$ (pin 29) to $G N D\left(V_{S S \_E X T}=0 V\right)$ to enable internal negative voltage generator.
2) Bypass mode: use $\mathrm{V}_{\text {SS_EXT }}$ (pin 29) to bypass and disable internal negative voltage generator.
3) $100 \%$ duty cycle, all bands, $50 \Omega$.
4) Pulsed, $5 \%$ duty cycle of $4620 \mu$ s period, $50 \Omega$.

## Electrical Specifications

Table 3 provides the PE42522 key electrical specifications at $25^{\circ} \mathrm{C}\left(Z_{S}=Z_{L}=50 \Omega\right)$, unless otherwise specified. Normal mode ${ }^{(1)}$ is at $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ and $\mathrm{V}_{\text {SS_EXT }}=0 \mathrm{~V}$. Bypass mode ${ }^{(2)}$ is at $\mathrm{V}_{\mathrm{DD}}=3.4 \mathrm{~V}$ and $\mathrm{V}_{\text {SS_EXT }}=-3.4 \mathrm{~V}$.

Table 3•PE42522 Electrical Specifications

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Operating frequency |  |  | 9 kHz |  | 26.5 GHz | As shown |
| Insertion loss ${ }^{(3)}$ | RFC-RFX | $\begin{aligned} & 9 \mathrm{kHz}-10 \mathrm{MHz} \\ & 10-3000 \mathrm{MHz} \\ & 3000-7500 \mathrm{MHz} \\ & 7500-10000 \mathrm{MHz} \\ & 10000-13500 \mathrm{MHz} \\ & 13500-18000 \mathrm{MHz} \\ & 18000-20000 \mathrm{MHz} \\ & 20000-24000 \mathrm{MHz} \\ & 24000-26500 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 0.70 \\ & 1.05 \\ & 1.15 \\ & 1.70 \\ & 1.70 \\ & 2.55 \\ & 3.15 \\ & 4.20 \\ & 5.30 \end{aligned}$ | $\begin{aligned} & 0.85 \\ & 1.40 \\ & 1.50 \\ & 2.15 \\ & 2.40 \\ & 3.25 \\ & 4.40 \\ & 5.45 \\ & 6.95 \end{aligned}$ | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |

Table 3•PE42522 Electrical Specifications (Cont.)

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Isolation | RFX-RFX | $\begin{aligned} & 9 \mathrm{kHz}-10 \mathrm{MHz} \\ & 10-3000 \mathrm{MHz} \\ & 3000-7500 \mathrm{MHz} \\ & 7500-10000 \mathrm{MHz} \\ & 10000-13500 \mathrm{MHz} \\ & 13500-18000 \mathrm{MHz} \\ & 18000-20000 \mathrm{MHz} \\ & 20000-24000 \mathrm{MHz} \\ & 24000-26500 \mathrm{MHz} \end{aligned}$ | $\begin{aligned} & 70 \\ & 62 \\ & 48 \\ & 42 \\ & 36 \\ & 26 \\ & 23 \\ & 19 \\ & 18 \end{aligned}$ | $\begin{aligned} & 80 \\ & 64 \\ & 50 \\ & 44 \\ & 38 \\ & 28 \\ & 25 \\ & 21 \\ & 20 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |
|  | RFC-RFX | $\begin{aligned} & 9 \mathrm{kHz}-10 \mathrm{MHz} \\ & 10-3000 \mathrm{MHz} \\ & 3000-7500 \mathrm{MHz} \\ & 7500-10000 \mathrm{MHz} \\ & 10000-13500 \mathrm{MHz} \\ & 13500-18000 \mathrm{MHz} \\ & 18000-20000 \mathrm{MHz} \\ & 20000-24000 \mathrm{MHz} \\ & 24000-26500 \mathrm{MHz} \end{aligned}$ | 65 <br> 61 <br> 55 <br> 48 <br> 37 <br> 28 <br> 26 <br> 21 <br> 19 | $\begin{aligned} & 73 \\ & 63 \\ & 58 \\ & 51 \\ & 39 \\ & 30 \\ & 28 \\ & 23 \\ & 22 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |
| Return loss (active port) ${ }^{(3)}$ | RFC-RFX | $\begin{aligned} & 9 \mathrm{kHz}-10 \mathrm{MHz} \\ & 10-3000 \mathrm{MHz} \\ & 3000-7500 \mathrm{MHz} \\ & 7500-10000 \mathrm{MHz} \\ & 10000-13500 \mathrm{MHz} \\ & 13500-18000 \mathrm{MHz} \\ & 18000-20000 \mathrm{MHz} \\ & 20000-24000 \mathrm{MHz} \\ & 24000-26500 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 23 \\ & 18 \\ & 16 \\ & 15 \\ & 20 \\ & 13 \\ & 7 \\ & 5 \\ & 6 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |
| Return loss (RFC port) ${ }^{(3)}$ | RFC-RFX | $\begin{aligned} & 9 \mathrm{kHz}-10 \mathrm{MHz} \\ & 10-3000 \mathrm{MHz} \\ & 3000-7500 \mathrm{MHz} \\ & 7500-10000 \mathrm{MHz} \\ & 10000-13500 \mathrm{MHz} \\ & 13500-18000 \mathrm{MHz} \\ & 18000-20000 \mathrm{MHz} \\ & 20000-24000 \mathrm{MHz} \\ & 24000-26500 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 23 \\ & 19 \\ & 27 \\ & 27 \\ & 20 \\ & 23 \\ & 10 \\ & 6 \\ & 7 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |
| Return loss (off port) | All ports | $\begin{aligned} & 9 \mathrm{kHz}-10 \mathrm{MHz} \\ & 10-3000 \mathrm{MHz} \\ & 3000-7500 \mathrm{MHz} \\ & 7500-10000 \mathrm{MHz} \\ & 10000-13500 \mathrm{MHz} \\ & 13500-18000 \mathrm{MHz} \\ & 18000-20000 \mathrm{MHz} \\ & 20000-24000 \mathrm{MHz} \\ & 24000-26500 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 30 \\ & 23 \\ & 15 \\ & 13 \\ & 14 \\ & 8 \\ & 6 \\ & 3 \\ & 2 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |

Table 3•PE42522 Electrical Specifications (Cont.)

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :---: | :---: | :---: |
| Input 0.1dB compression <br> point ${ }^{(4)}$ | RFC-RFX |  | Fig. 2 <br> Fig. 3 <br> Fig. |  | dBm <br> dBm <br> dBm |  |
| Input IP2 | RFC-RFX | $10-18000 \mathrm{MHz}$ | 121 |  | dBm |  |
| Input IP3 | RFC-RFX | $10-18000 \mathrm{MHz}$ |  | 59 |  | dBm |
| Settling time |  | $50 \%$ CTRL to 0.05 dB final value | 7 | 10 | $\mu \mathrm{~s}$ |  |
| Switching time |  | $50 \%$ CTRL to $90 \%$ or $10 \%$ of RF |  | 3 | 4.5 | $\mu \mathrm{~s}$ |

Notes:

1) Normal mode: connect $\mathrm{V}_{\text {SS_EXT }}(\operatorname{pin} 29)$ to $G N D\left(\mathrm{~V}_{\text {SS_EXT }}=0 \mathrm{~V}\right)$ to enable internal negative voltage generator.
2) Bypass mode: use $V_{S S \_E X T}$ (pin 29) to bypass and disable internal negative voltage generator.
3) High frequency performance can be improved by external matching (see Figure 19-Figure 21).
4) The input 0.1 dB compression point is a linearity figure of merit. Refer to Table 2 for the RF input power ( $50 \Omega$ ).

## Switching Frequency

The PE42522 has a maximum 25 kHz switching rate in normal mode (pin 29 tied to ground). A faster switching rate is available in bypass mode (pin 29 tied to $\mathrm{V}_{\text {SS_EXT }}$ ). The rate at which the PE42522 can be switched is then limited to the switching time as specified in Table 3.
Switching frequency describes the time duration between switching events. Switching time is the time duration between the point the control signal reached $50 \%$ of the final value and the point the output signal reaches within $10 \%$ or $90 \%$ of its target value.

## Spur-Free Performance

The typical spurious performance of the PE42522 in normal mode is -125 dBm (pin 29 tied to ground). If spur-free performance is desired, the internal negative voltage generator can be disabled by applying a negative voltage to $\mathrm{V}_{\text {SS_EXT }}$ ( pin 29 ).

## Hot-Switching Capability

The maximum hot switching capability of the PE42522 is 20 dBm from 1.4 MHz to 18 GHz . The maximum hot switching capability below 1.4 MHz and above 18 GHz does not exceed the maximum RF CW terminated power, see Figure 2-Figure 4. Hot switching occurs when RF power is applied while switching between RF ports.

## Control Logic

Table 4 provides the control logic truth table for PE42522.

## Table 4•Truth Table for PE42522

| State | V1 |
| :---: | :---: |
| RF1 ON | 0 |
| RF2 ON | 1 |

Figure $2 \cdot$ Power De-rating Curve ( $9 \mathrm{kHz}-18 \mathrm{GHz}$ ) @ $25^{\circ} \mathrm{C}$ Ambient (50 )


Figure $3 \cdot$ Power De-rating Curve ( $9 \mathrm{kHz}-18 \mathrm{GHz}$ ) @ $85^{\circ} \mathrm{C}$ Ambient (50 )


Figure $4 \cdot$ Power De-rating Curve (16-26.5 GHz) @ $25^{\circ} \mathrm{C}$ and $85{ }^{\circ} \mathrm{C}$ Ambient (50 )


## Typical Performance Data

Figure 5-Figure 17 show the typical performance data at $25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}\left(\mathrm{Z}_{\mathrm{S}}=\mathrm{Z}_{\mathrm{L}}=50 \Omega\right)$ unless otherwise specified.

Figure $5 \cdot$ Insertion Loss (RFC-RFX) $\left.{ }^{*}\right)$
Note: * High frequency performance can be improved by external matching (see Figure 19-Figure 21).


Figure $6 \cdot$ Insertion Loss vs Temperature (RFC-RFX)(*)
Note: * High frequency performance can be improved by external matching (see Figure 19-Figure 21).
$----40^{\circ} \mathrm{C}=+25^{\circ} \mathrm{C},-,-\cdot+85^{\circ} \mathrm{C}$


## Figure 7•Insertion Loss vs $V_{D D}\left(\right.$ RFC-RFX) ${ }^{* *}$

Note: * High frequency performance can be improved by external matching (see Figure 19-Figure 21).


Figure $8 \cdot$ RFC Port Return Loss vs Temperature ${ }^{* *}$
Note: * High frequency performance can be improved by external matching (see Figure 19-Figure 21).


Figure 9•RFC Port Return Loss vs $V_{D D^{*}}{ }^{*}$
Note: * High frequency performance can be improved by external matching (see Figure 19-Figure 21).


Figure 10 • Active Port Return Loss vs Temperature ${ }^{(*)}$
Note: * High frequency performance can be improved by external matching (see Figure 19-Figure 21).

$$
---40^{\circ} \mathrm{C}-+25^{\circ} \mathrm{C},-,-+85^{\circ} \mathrm{C}
$$



Figure 11 • Active Port Return Loss vs $V_{D D}{ }^{(*)}$
Note: * High frequency performance can be improved by external matching (see Figure 19-Figure 21).



Figure 12•Terminated Port Return Loss vs Temperature


Figure $13 \cdot$ Terminated Port Return Loss vs $V_{D D}$


Figure 14•Isolation vs Temperature (RFX-RFX)


Figure 15•Isolation vs $V_{D D}(R F X-R F X)$


Figure $16 \cdot$ Isolation vs Temperature (RFC-RFX)


Figure $17 \cdot$ Isolation vs $V_{D D}(R F C-R F X)$


## High Frequency Performance with External Matching

High frequency insertion loss and return loss can be further improved by external tuning traces in the customer application board layout. Figure 18 is a sample matching network using ideal elements. Figure 19-Figure 21 show the simulated insertion loss and return loss improvement using the matching network.

Figure 18•PE42522 Matching Network


Additional information on high frequency performance with external matching can be found in Application Note 41, PE42522/523-High Frequency Performance Improvement Through Narrowband Matching.

Figure 19•Insertion Loss (RFC-RFX) With or Without Matching ${ }^{(*)}$
Note: * For reference only.


Figure 20 • Active Port Return Loss With or Without Matching ${ }^{*}$ )
Note: * For reference only.


Figure 21 • RFC Port Return Loss With or Without Matching ${ }^{(*)}$
Note: * For reference only.


## Evaluation Kit

The SPDT switch evaluation board was designed to ease customer evaluation of Peregrine's PE42522. The RF common port is connected through a $50 \Omega$ transmission line via the SMA connector, J1. RF1 and RF2 ports are connected through $50 \Omega$ transmission lines via SMA connectors J4 and J3 respectively. A $50 \Omega$ through transmission line is available via SMA connectors J 6 and J 7 , which can be used to de-embed the loss of the PCB. J 13 provides DC and digital inputs to the device.
The board is constructed of a two metal layer material with a total thickness of 38 mils. The top RF layer is Rogers 4360 material with a thickness of 32 mils and the $\varepsilon_{r}=6.4$. The bottom layer provides ground for the transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 18 mils, trace gaps of 7 mils and metal thickness of 2.1 mils.
For the true performance of the PE42522 to be realized, the PCB must be designed in such a way that RF transmission lines and sensitive DC I/O traces are well isolated from one another. High frequency insertion loss and return loss can be further improved by external tuning traces in the customer application board layout. For further details, see "High Frequency Performance with External Matching".
Please note that this is a generic PCB and is being used for multiple parts. Pin labeled V2 is GND.
Figure 22•Evaluation Kit Layout for PE42522


## Pin Information

This section provides pinout information for the PE42522. Figure 23 shows the pin map of this device for the available package. Table 5 provides a description for each pin.

Figure 23 • Pin Configuration (Top View)


Table 5 • Pin Descriptions for PE42522

| Pin No. | Pin Name | Description |
| :---: | :---: | :---: |
| $\begin{gathered} 1,3-11 \\ 13-21,23 \\ 25-27 \end{gathered}$ | GND | Ground |
| 2 | RF2 ${ }^{(1)}$ | RF port 2 |
| 12 | RFC ${ }^{(1)}$ | RF common |
| 22 | $R F 1{ }^{(1)}$ | RF port 1 |
| 24 | $\mathrm{V}_{\mathrm{DD}}$ | Supply voltage (nominal 3.3V) |
| 28 | V1 | Digital control logic input 1 |
| 29 | $\mathrm{V}_{\text {SS_EXT }}{ }^{(2)}$ | External $\mathrm{V}_{\text {SS }}$ negative voltage control |
| Pad | GND | Exposed pad: ground for proper operation |
| Notes: <br> 1) RF pins 2,12 and 22 must be at 0 VDC. The RF pins do not require DC blocking capacitors for proper operation if the 0 VDC requirement is met. <br> 2) Use $V_{S S}$ EXT (pin 29) to bypass and disable internal negative voltage generator. Connect $\mathrm{V}_{\text {SS_EXT }}(\mathrm{pin} 29)$ to $\mathrm{GND}\left(\mathrm{V}_{\text {SS_EXT }}=\right.$ OV ) to enable internal negative voltage generator. |  |  |

## Packaging Information

This section provides packaging data including the moisture sensitivity level, package drawing, package marking and tape-and-reel information.

## Moisture Sensitivity Level

The moisture sensitivity level rating for the PE42522 in the 29 -lead $4 \times 4 \mathrm{~mm}$ LGA package is MSL3.

## Package Drawing

Figure $24 \cdot$ Package Mechanical Drawing for 29-lead $4 \times 4 \times 0.91 \mathrm{~mm}$ LGA


| Pin Number | Pin Size $(\mathrm{x}, \mathrm{y})$ | X Coordinate | Y Coordinate |
| :---: | :---: | :---: | :---: |
| 1 | $(0.285 \times 0.280)$ | 1.7575 | 1.7434 |
| 2 | $(0.250 \times 0.250)$ | 1.7750 | 1.2750 |
| 3 | $(0.285 \times 0.280)$ | 1.7575 | 0.8466 |
| 4 | $(0.285 \times 0.280)$ | 1.7575 | 0.3982 |
| 5 | $(0.285 \times 0.280)$ | 1.7575 | -0.0502 |
| 6 | $(0.285 \times 0.280)$ | 1.7575 | -0.4986 |
| 7 | $(0.250 \times 0.250)$ | 1.7750 | -0.9670 |
| 8 | $(0.285 \times 0.280)$ | 1.7575 | -1.3954 |
| 9 | $(0.280 \times 0.285)$ | 1.3652 | -1.7575 |
| 10 | $(0.280 \times 0.285)$ | 0.9168 | -1.7575 |
| 11 | $(0.280 \times 0.285)$ | 0.4684 | -1.7575 |
| 12 | $(0.250 \times 0.250)$ | 0 | -1.7750 |
| 13 | $(0.280 \times 0.285)$ | -0.4684 | -1.7575 |
| 14 | $(0.280 \times 0.285)$ | -0.9168 | -1.7575 |
| 15 | $(0.280 \times 0.285)$ | -1.3652 | -1.7575 |
| 16 | $(0.285 \times 0.280)$ | -1.7575 | -1.3954 |
| 17 | $(0.250 \times 0.250)$ | -1.7750 | -0.9670 |
| 18 | $(0.285 \times 0.280)$ | -1.7575 | -0.4986 |
| 19 | $(0.285 \times 0.280)$ | -1.7575 | -0.0502 |
| 20 | $(0.285 \times 0.280)$ | -1.7575 | 0.3982 |
| 21 | $(0.285 \times 0.280)$ | -1.7575 | 0.8466 |
| 22 | $(0.250 \times 0.250)$ | -1.7750 | 1.2750 |
| 23 | $(0.285 \times 0.280)$ | -1.7575 | 1.7434 |
| 24 | $(0.210 \times 0.250)$ | -1 | 1.7750 |
| 25 | $(0.210 \times 0.250)$ | -0.600 | 1.7750 |
| 26 | $(0.210 \times 0.250)$ | -0.200 | 1.7750 |
| 27 | $(0.210 \times 0.250)$ | 0.200 | 1.7750 |
| 28 | $(0.210 \times 0.250)$ | 0.600 | 1.7750 |
| 29 | $(0.210 \times 0.250)$ | 1 | 1.7750 |

Figure 25 • Package Marking Specifications for PE42522


$$
\begin{aligned}
& =\text { Pin } 1 \text { indicator } \\
\mathrm{YY} & =\text { Last two digits of assembly year } \\
\mathrm{WW} & =\text { Assembly work week } \\
\mathrm{ZZZZZZ} & =\text { Assembly lot code (maximum six characters) }
\end{aligned}
$$

## Tape and Reel Specification

Figure $26 \cdot$ Tape and Reel Specifications for 29-lead $4 \times 4 \times 0.91 \mathrm{~mm}$ LGA


| A0 | 4.35 |
| :---: | :---: |
| B0 | 4.35 |
| K0 | 1.10 |
| D0 | $1.50+0.10 /-0.00$ |
| D1 | 1.50 min |
| E | $1.75 \pm 0.10$ |
| F | $5.50 \pm 0.05$ |
| P0 | 4.00 |
| P1 | 8.00 |
| P2 | $2.00 \pm 0.05$ |
| T | $0.30 \pm 0.05$ |
| W0 | $12.00 \pm 0.30$ |

Notes:

1. 10 Sprocket hole pitch cumulative tolerance $\pm 0.2$
2. Camber in compliance with EIA 481
3. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole

Dimensions are in millimeters unless otherwise specified


Device Orientation in Tape

## Ordering Information

Table 6 lists the available ordering codes for the PE42522 as well as available shipping methods.

## Table 6 • Order Codes for PE42522

| Order Codes | Description | Packaging | Shipping Method |
| :--- | :---: | :---: | :---: |
| PE42522A-X | PE42522 SPDT RF switch | 29-lead $4 \times 4 \mathrm{~mm}$ LGA | 500 units $/$ T\&R |
| EK42522-02 | PE42522 Evaluation kit | Evaluation kit | $1 /$ box |

## Document Categories

## Advance Information

The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

## Preliminary Specification

The datasheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

## Product Specification

The datasheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

## Not Recommended for New Designs (NRND)

This product is in production but is not recommended for new designs.

## End of Life (EOL)

This product is currently going through the EOL process. It has a specific last-time buy date.

## Obsolete

This product is discontinued. Orders are no longer accepted for this product.

## Sales Contact

For additional information, contact Sales at sales@psemi.com.

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